Excitonic Emission of Monolayer Semiconductors Near-Field Coupled to High-Q Microresonators

Clément Javerzac-Galy,† Anshuman Kumar,† Ryan D. Schilling,† Nicolas Piro,‡ Sina Khorasani,‡ Matteo Barbone,§ Ilya Goykhman,§ Jacob B. Khurgin,¶ Andrea C. Ferrari,§ and Tobias J. Kippenberg*,†

†Institute of Physics, École Polytechnique Fédérale de Lausanne (EPFL), Lausanne CH-1015, Switzerland
‡Vienna Center for Quantum Science and Technology (VCQ), University of Vienna, 1090 Vienna, Austria
§Cambridge Graphene Centre, University of Cambridge, Cambridge CB3 0FA, U.K.
¶Department of Electrical and Computer Engineering, Johns Hopkins University, Baltimore, Maryland 21218, United States

ABSTRACT: We present quantum yield measurements of single layer WSe₂ (1L-WSe₂) integrated with high-Q (Q > 10⁶) optical microdisk cavities, using an efficient (η > 90%) near-field coupling scheme based on a tapered optical fiber. Coupling of the excitonic emission is achieved by placing 1L-WSe₂ in the evanescent cavity field. This preserves the microresonator high intrinsic quality factor (Q > 10⁶) below the bandgap of 1L-WSe₂. The cavity quantum yield is QY_c ≈ 10⁻³, consistent with operation in the broad emitter regime (i.e., the emission lifetime of 1L-WSe₂ is significantly shorter than the bare cavity decay time). This scheme can serve as a precise measurement tool for the excitonic emission of layered materials into cavity modes, for both in plane and out of plane excitation.

KEYWORDS: 2D materials, whispering gallery mode resonator, electronic and optical properties, WSe₂, transition metal dichalcogenides

Transition metal dichalcogenides (TMDs) are promising for optoelectronic applications, including light emitting devices, optical modulators, and photodetectors. These exploit the fact that their optical response is dominated by strong excitonic transitions, with large binding energies of a few hundred meV, as a result of reduced screening. The broken inversion symmetry, in combination with the strong spin–orbit coupling, leads to the possibility of valley optoelectronic devices. Monolayer TMDs can have a direct bandgap. They could be integrated in cavities with the aim of enhancing the light matter interaction via the increased optical density of states. Enhanced interactions have been demonstrated with layered materials (LMs) integrated with photonic crystal cavities, distributed Bragg cavities, and microdisks. A key metric of light emission in such integrated systems is the cavity quantum yield (QY_c), i.e., the number of photons emitted into the cavity mode for each absorbed pump photon. QY_c is often limited by the nonradiative recombination of excitons in TMDs, which mostly arises from defects and Auger effects. An accurate QY_c measurement tool is needed to attain an improved physical understanding of emission properties in these systems, and for evaluation of future optoelectronic devices performance, such as their efficiency or expected output power. Conventional techniques for QY_c measurements, as they do not collect the light directly from the cavity mode.

A precise QY_c characterization is also needed to establish lasing operation in cavity-integrated LMs, which have recently captured significant interest. In general, the determination of the lasing threshold in microlaserers is compounded by the fact that they can exhibit a large (close to unity) spontaneous emission coupling factor (β), defined as the fraction of the total spontaneous emission captured into the cavity mode, as typical for devices with a small wavelength-size mode volume. For emitters spectrally broader than the cavity mode (i.e., which decay significantly faster than the bare cavity), the Purcell effect, i.e., the enhancement of spontaneous emission rate by a cavity, is dominated by the emitter line width. Specifically in this broad emitter regime, also referred to as the bad emitter regime in cavity quantum electrodynamics (cQED), a large (close to 1) β cannot be achieved, and the achievable enhancement is governed by both emitter line width and cavity line width. This regime also applies to refs 15, 21, and 22, which consider LM coupled to nanophotonic cavities, where the emission was interpreted as lasing. However, the inferred β in these studies (∼0.1–0.5) are incompatible with the broad emitter regime.

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Importantly, regardless of the Purcell effect, the transition from spontaneous to stimulated emission dominated regime occurs in any laser, irrespective of implementation, when the mean photon number in the cavity lasing mode exceeds unity ($\bar{n}_c > 1$). The underlying reason is that stimulated and spontaneous emission into the cavity differ only by the bosonic mode occupation of the lasing mode.\textsuperscript{27} This condition has also been referred to as the quantum threshold\textsuperscript{28} in the context of early studies of microlasers.

This requirement implies (see Methods) that the lowest possible threshold to achieve a unity cavity photon number in the lasing mode (for an optically pumped ideal single mode laser), $G_{\text{th,ideal}}$ is given by a pump flux that equals the cavity decay rate.\textsuperscript{28} In fact, for an optically pumped microsensor, assuming $\beta = 1$ and neglecting nonradiative losses, the pumping rate of the cavity mode $G_{\text{th}} = P_\text{th}/\hbar\omega_\text{p}$ with $P_\text{th}$ the threshold pump power and $\hbar\omega_\text{p}$ the pump photon energy, should equal or exceed the cavity decay rate $\kappa_\text{tot} = \alpha_\text{lasing}/Q$ with $\alpha_\text{lasing}$ the lasing angular frequency and $Q$ the loaded quality factor at the lasing frequency. For $\beta = 1$ and an ideal (lossless) emitter, the lowest possible threshold depends only on the total cavity loss rate $\kappa_\text{tot}$.

This general condition is satisfied in a variety of lasers at the micro- and nanoscale, such as photonic crystal defect lasers coupled to quantum wells\textsuperscript{30} ($G_{\text{th}} \approx 3 \times 10^{16}$ s$^{-1} > G_{\text{th,ideal}} \approx K_\text{tot}$ $\approx 6 \times 10^{12}$ s$^{-1}$, where nonradiative channels are negligible\textsuperscript{30}) and rare earth-doped microdisc lasers\textsuperscript{31} ($G_{\text{th}} \approx 3 \times 10^{14}$ s$^{-1} > G_{\text{th,ideal}} \approx 6 \times 10^{9}$ s$^{-1}$). However, in ref 21, where lasing from 1L-WSe$_2$ was claimed, this condition is not fulfilled: $G_{\text{th}} \approx 1 \times 10^{11}$ s$^{-1} < G_{\text{th,ideal}} \approx 1 \times 10^{12}$ s$^{-1}$, even neglecting nonradiative relaxation processes. More generally there are growing concerns on rigorous identification of lasing.\textsuperscript{32} The increasing research effort on LMs and heterostructures of interest for nanoscale light sources needs a precise technique, which can characterize the number of photons absorbed and emitted, to verify if the threshold condition for lasing is reachable or met.

Here, we measure and characterize the optical response of cavity integrated TMDs (and the exciton emission) by using a tapered fiber coupling scheme\textsuperscript{33} to both pump 1L-TMD and collect the emission, thereby determining $Q_Y$, upon optical pumping. This method enables the determination of the power absorbed by 1L-TMD, as well as the photons emitted from it into the cavity modes, via the determination of the external (taper fiber induced) and intrinsic cavity decay rates. This allows us to calculate precisely the $Q_Y$. Moreover, tapered fiber excitation of the TMD integrated microsensator allows us to excite both in plane and out of plane polarization modes, in principle enabling selective excitation of dark and bright excitons, which couple to distinct polarizations.\textsuperscript{33,34} One may let one of the two available orthogonal polarizations at each wavelength enter the resonator and interact with the LM. We demonstrate our approach by measuring $Q_Y$ of 1L-WSe$_2$ integrated with a silica microdisc resonator. We show that this maintains high intrinsic $Q$ ($>10^6$ below bandgap, corresponding to an optical Finesse $> 10^4$), higher than in previous reports,\textsuperscript{15,21} enabling the fabrication of optoelectronic devices without need of heterogeneous integration.\textsuperscript{35}

The system under study consists of a SiO$_2$ microdisc, with a 1L-WSe$_2$ flake deposited on its surface. This is prepared as follows. A 750 nm thick SiO$_2$ film is grown on a Si(100) wafer by thermal oxidation. Wet etching in buffered hydrofluoric acid forms the microdisc.\textsuperscript{36} The wet etch mask is defined by electron beam lithography in ZEP 520A photosresist. A postdevelopment bake is performed to reduce stress in the polymer and increase adhesion. The resulting microdiscs have diameters from $\sim$16 to $\sim$38 $\mu$m. They have a sidewall wedge angle of $10^\circ$, characteristic of such wet etching processes,\textsuperscript{37} which serves two purposes: first, as shown in Figure 1, it results in the mode being shifted away from the disk edge, thereby reducing scattering losses.\textsuperscript{31} Second, it enables tapered fiber coupling in contact mode (away from the mode center), thereby reducing cavity power fluctuations due to taper vibrations. Finally, the microdiscs are undercut with potassium hydroxide to form an air-clad whispering gallery mode (WGM) resonator.\textsuperscript{38} The microdiscs sit on $\sim$200 $\mu$m Si Mesa pillars to prevent the tapered fiber from being in contact with the substrate during coupling. They then undergo oxygen plasma cleaning before 1L-WSe$_2$ transfer.

1L-WSe$_2$ is prepared and integrated on the microdiscs as follows. Bulk WSe$_2$ (HQ Graphene) is characterized before exfoliation by Raman spectroscopy as described in ref 39. This is then exfoliated on a polydimethylsiloxane layer by micro-mechanical cleavage. 1L-WSe$_2$ flakes are identified by optical contrast.\textsuperscript{40} Selected flakes are then transferred onto the
microdisks via an all-dry viscoelastic transfer technique, exploiting their higher adhesion to SiO₂. After transfer, the flakes are characterized by Raman spectroscopy (Figure 1d) at 532 nm excitation. The main features are the A₁' + E' mode at ~249.5 cm⁻¹ and the 2LA(M). The thickness is then validated by PL (Figure 2a). This confirms the transfer and that the process does not damage the samples.

A scanning electron microscopy (SEM) image of the 1L-WSe₂ integrated microdisk is shown in Figure 1a. The WGM transverse mode profile is located within the wedge, as indicated by the finite element simulation (using Comsol...
Multiphysics) in Figure 1b. Thus, the 1L-WSe2 flake sits in the near-field of the optical mode. The 1L-WSe2 is modeled as a ~0.65 nm thick dielectric. The SEM imaging also allows to verify that the transfer process does not leave PDMS residues, organic residues, or defects on the microdisk.

In order to allow excitation and collection of emission from the 1L-WSe2, we use a near field coupling scheme via a tapered optical fiber, whereby phase matching between WGM and tapered fiber mode is obtained by translating the disk along the taper waist. For a coupling ideality of unity, the coupling parameter is given by:

\[ \frac{\kappa_{ex}}{\kappa_0} = \frac{1 \pm \sqrt{T}}{1 \mp \sqrt{T}} \]  

where \( \kappa_0 \) is the intrinsic loss rate of the microresonator, which is the sum of radiative and absorption losses. The latter are dominated by 1L-WSe2 for wavelengths above the bandgap because of interband absorption. \( \kappa_{ex} \) is the photon loss rate due to the external coupling of light to the tapered fiber, and \( T \) is the transmission of the microresonator on resonance. The upper signs are used for the overcoupled regime \( (\kappa_0 < \kappa_{ex}) \) and the lower signs for the under-coupled regime \( (\kappa_0 > \kappa_{ex}) \). T vanishes for critical coupling \( (\kappa_0 = \kappa_{ex}) \).

We then record the transmission spectrum while scanning an external cavity diode laser (ECDL) over resonance for different central wavelengths and taper waist radii. An ECDL is necessary because we need mode-hop free excitation over the free spectral range, which is typically sub-THz. The corresponding total line width \( (\kappa_{tot} = \kappa_{ex} + \kappa_0) \) is measured with a calibrated fiber loop cavity. Thus, with the knowledge of \( \kappa_{tot} \) and \( T \), \( \kappa_{ex} \) and \( \kappa_0 \) are determined. This is one of the key features of our approach, which enables precise characterization of photon emission and absorption rates of LMs.

Our measurement setup is presented schematically in Figure 2. Laser light through the ECDL is split into two parts: one passes through a fiber loop cavity (calibration branch) and another through the tapered fiber, which is coupled to the cavity (cavity branch). Both branches have independent fiber polarization controllers. For line width calibration, the reference and the cavity branch are detected and monitored on an oscilloscope. The free spectral range of the fiber loop cavity is known through an independent calibration via a phase modulation measurement. In our setup, the fiber loop cavity serves to calibrate the time axis on the oscilloscope. In this way, the total line width and the transmission resonance are recorded automatically. For measurement of the spectrum, the output of the cavity branch is sent to a spectrometer. A high pass filter (cut-on wavelength of 660 nm) is employed prior to the spectrometer to cancel out the pump.

We first characterize the bare microdisks in a one-color scheme, where we excite and collect at the same laser excitation wavelength. We use three excitation wavelengths: below bandgap (850 nm), near excitonic transition (770 nm), and above bandgap (635 nm). We consistently observe Q factors >5 x 10^5 for the bare disks at all three wavelengths. An example transmission spectrum for the bare disk is plotted in Figure 2c for \( \lambda = 850 \) nm, where a double Lorentzian fit leads to \( Q_0 = \omega / \kappa_0 \approx 1 \times 10^7 \). Nanoscale surface defects, such as small imperfections, cause the high-Q resonances to split, due to the coupling between the clockwise and counterclockwise propagating WGMs.

Next, we measure the line widths for the 1L-WSe2 coated disks. As shown in Figure 2d, the intrinsic \( Q_0 \) is maintained at a high value (e.g., \( 4 \times 10^6 \) at 850 nm). We attribute the small reduction in \( Q_0 \) at this wavelength to scattering at the 1L-WSe2 edge.

We note that our disk platform provides Q (\( >10^8 \)) and Finesse (\( >10^6 \)) below bandgap, exceeding previous reports of cavity integrated LMs. For excitations above the bandgap, the Q (\( \sim 10^5 \)) and Finesse (\( \sim 10 \)) are reduced, demonstrating absorption dominated behavior, due to the 1L-WSe2.

The near field coupling to the microdisk via a tapered fiber enables, in principle, a precise determination of the photons absorbed, as well as those emitted into the cavity modes, when the loss rate at the pump wavelength is dominated by the LM absorption. Our method can be employed to characterize QY, where QY is the emission rate into the cavity modes and G is the pumping (generation) rate.

The 1L-WSe2 is excited using a tunable pump laser at \( \lambda = 635 \) nm via near field coupling using a tapered fiber. The pump frequency is tuned to a resonance of the WGM of the microdisk. The resulting 1L-WSe2 PL (at \( \sim 760 \) nm) is coupled into the WGM of the microdisk near the 1L-WSe2 A-exciton transition energy. The exciton emission coupled to the WGM is then collected again via the same near-field coupled tapered fiber. Thus, unlike the pristine microdisk case, this
measurement employs a two-color scheme, where pump and emission wavelengths are different.

Figure 2b indicates that the resulting emission consists of background-free, cavity-enhanced PL, with several peaks arising from the WGMs of the microdisk. References 15 and 50 reported emission measurement schemes on cavity integrated LMs, with cavity modes superimposed on a free-space PL background.15 Our near field tapered fiber scheme enables collection only of the PL which is coupled into the cavity modes, without background PL arising from coupling into free-space modes. The PL collection efficiency of the photons emitted into the cavity modes in our setup is defined as \( \eta = \kappa_{em}/\kappa_{tot} \). Unlike free space collection techniques, we are not limited by the numerical aperture of the objective, and under appropriate phase matching, \( \eta > 90\% \) is achievable, when operating as strongly overcoupled.46

The peaks in our taper-collected PL are spaced by the free spectral range (FSR) that characterizes the separation of two longitudinal resonances of the disk: \( \text{FSR} = \lambda^2/(2\pi n R) \), where \( \lambda \) is the central wavelength, \( n \) is the effective mode index, and \( R \) is the microdisk radius. In Figure 2b, FSR \( \sim 8 \) nm, as expected from \( R \sim 8 \) \( \mu \)m. Secondary peaks might arise from either fundamental modes of the orthogonal polarization or from higher order modes of the microdisk.

We observe an asymmetric line shape in the free-space PL, which is well fitted to the sum of two Voigt peaks, arising from the neutral and charged excitons.24 Although the rigorous identification of the lower energy peak would require a doping-dependent PL measurement, it is usually attributed to trionic emission.55,56 Thus, we attribute the asymmetric shape of the envelope of our cavity PL to the spontaneous emission profile of the 1L-WSe\(_2\). The maximum of the cavity PL spectrum does not coincide with that of the free-space PL.

Figure 3a shows the enhancement of PL from 1L-WSe\(_2\) integrated microdisk as the excitation power is increased from \( \sim 0.5 \) to \( \sim 250 \) \( \mu \)W. Scattered light of the PL coupled into the WGM can be observed. In Figure 3b, FSR \( \sim 3 \) nm and \( \eta \sim 93\% \). This scattered PL is a fraction (see Methods) of the total emission; the rest goes into the WGMs and nonradiative channels. Figure 3b shows the shape of the PL spectrum as a function of the excitation power.

Our approach for measuring line widths and \( T \) allows us to determine the values of the internal and external coupling rates at both pump and emission wavelengths. This enables us to calibrate the pump power input as well as the emission output. Thus, this technique enables precise determination of the QY of cavity-integrated LMs. The data in Figure 3c include this calibration, giving QY \( \sim 0.10\% \) at room temperature. The power dependences of the different PL peaks are linear and follow the PL spectrum intensity in our low power regime.

When an emitter is placed near a cavity, its emission rate into the cavity mode is modified compared to free-space. When this rate is enhanced, it is referred to as Purcell enhancement.27 For a high-Q cavity this can give a QY increase.38 The simulated peak Purcell enhancement factor for each cavity mode is

\[
 F_p = \left(3/4\pi^2\right)(\lambda_0/n)^2Q_i/V_{eff} 
\]

where \( \lambda_0/n \) is the wavelength within the material and Q\(_i\) and \( V_{eff} \) are the quality factor and mode volume of the cavity. This is \( \sim 8-14 \) for the different mode families within our window of operation. However, eq 2 is only applicable when the cavity line width dominates that of the emitter.59 This explains why no Purcell enhancement is observed in our experiment, since our cavity line width is \(< 0.01 \) nm, and the emitter line width is \( > 10 \) nm. The total emission rate is determined by the integral of the product of the spectral density of the excited states in the emitter and the photon density of states. This can be understood in terms of an approximate expression for the Purcell factor (on resonance), which for one of the cavity modes \( i \) is given by

\[
 F_{p,i} = \frac{3}{4\pi^2} \frac{(\lambda/n)^2}{V_{eff}} \left( \frac{1}{Q_{em}} + \frac{1}{Q_{c,i}} \right)^{-1} 
\]

where \( Q_i \) and \( Q_{em} \) are the quality factors of the cavity mode \( i \) and the emitter. Due to the large emission line width (\( \sim 50 \) meV) (see Figure 2) of 1L-WSe\(_2\) compared to the cavity modes, the system is in the broad emitter regime. This leads to a reduction in the Purcell factor limiting the spontaneous emission enhancement.

The error in the linearly fitted QY\(_{pl}\) (without taking into account the error in the data collected), as presented in Figure 3c, is \( \sim 5\% \). This is attributed to the fact that the QY\(_{pl}\) of the 1L-WSe\(_2\) depends on pump intensity, similar to what was observed for exfoliated 1L-MoS\(_2\).16 Thus, any linear fit varying pump power is expected to produce errors. At higher power (\( \sim 250 \) \( \mu \)W in our case), a degradation of the QY\(_{pl}\) with increasing pump power can occur due to exciton-exciton annihilation,61 as well as defect mediated nonradiative recombination (see Methods). This will limit the efficiency of light sources based on 1L-WSe\(_2\).

We next ascertain the feasibility of achieving lasing. The low QY\(_{pl}\), \(< 0.10\% \), is insufficient for a given pump power to reach a single intracavity photon per mode \( \sim G\cdot QY_{pl}/(M\kappa_{tot}) \sim 0.6 \) at the highest pump power, \( \sim 250 \) \( \mu \)W, as required for the quantum threshold lasing condition discussed earlier. This explains why no narrowing of the emission lines is observed. To achieve lasing, QY\(_{pl}\) must be increased by at least one order of magnitude by reducing nonradiative recombinations16 as well as increasing Q\(_{em}\), which contributes to the cavity decay rate, QY\(_{em}\), and the number of cavity modes, M (see Methods). Factors such as \( \beta \) and Purcell enhancement do not help reducing the threshold. While increasing \( \beta \) is often presented as a means to reduce the laser threshold, this is almost always achieved by reducing the active volume of the laser,62 which, however, keeps the pumping density per unit of volume constant. Similarly, the Purcell enhancement does not assist as both stimulated and spontaneous emission rate increase by the same amount.57,62

By optimizing the mode volume, our platform can be designed to show high (>1) effective Purcell factors for enhancing the QY\(_{pl}\) of LMs.58 In addition, methods have been reported to increase the LM QY, e.g., via encapsulation63 or chemical surface treatment.16

In summary, we presented a technique for measuring the cavity coupled excitonic emission of high-Q microresonators integrated with LMs, using a near-field coupled tapered fiber and a LM-integrated high-Q microdisk. We presented QY measurements of 1L-WSe\(_2\) obtaining \( \sim 10^{-3} \), in agreement with operation in the broad emitter regime, i.e., the emission lifetime of 1L-WSe\(_2\) significantly exceeds the cavity decay rate. These results contrast previous work on LM coupled to microcavities,5,21,22 which did not consider this regime and applies equally to nanophotonic cavities due to the short excitonic emission lifetime of the LM. The low cavity quantum yields in
the present case prevents reaching the threshold condition of lasing. Moreover, at high power, exciton—exciton annihilation will limit the efficiency of light sources based on 1L-WSe2.4 For an ideal laser (eq 1), the pump rate needed to satisfy the threshold condition is given by

$$G_{th} = 1 + \frac{\kappa_{tot}}{\beta}$$

where $\kappa_{tot}$ is the total spontaneous emission rate, $\beta$ is the spontaneous emission coupling factor, and $G_{th}$ is the pump rate. For an ideal laser, $G_{th} = 1$.

For the less than ideal laser, accounting for the nonradiative recombination as well as $\beta < 1$ and multimodes, we get

$$G_{th} > M \kappa_{tot}/QY$$

(8)

In particular, below threshold (when stimulated emission does not occur), one has $\kappa_t \approx G/QY/(M \kappa_{tot})$.

The spacing between cavity modes is given by $\Delta \lambda_{FSR} = 2\pi \lambda_{tot}^{2}$, where $\lambda_{tot}$ is the optical path length of the cavity, i.e., for a microdisk $l = 2m_{\pi}R$, where $m_{\pi}$ is the effective mode index and $R$ is the microdisk radius. The width of emission of 1L-WSe2 is $\Delta \omega_{em} = \frac{\omega}{QY}$. The total number of modes in the cavity is then

$$M \approx \frac{\Delta \omega_{em}}{2\pi \Delta \lambda_{FSR}} = \frac{l}{\lambda QY_{em}}$$

(9)

The lasing threshold depends only on $\kappa_{tot}$, $QY_{em}$ and $M$ (eq 8). The cavity finesse is given by

$$F = \frac{QY_{em}}{\Delta \lambda} = \frac{l}{k_{tot}}$$

(10)

$\kappa_{tot}$ is inversely proportional to the cavity length. From eqs 8–10, we get

$$G_{th} \approx \frac{\omega}{QY_{em} F}$$

(11)

determined only by $QY_{em}$, $F$, and $\lambda$. Equation 13 expresses the relation between $QY_{em}$ and $\beta_{eff}$, highlighting that $QY_{em}$ embeds the geometrical aspect of the cavity and the nonradiative contribution. $\beta_{eff}$ and Purcell enhancement do not appear in the threshold (eq 11): $QY_{em}$ includes all these contributions. $\beta_{eff}$ and Purcell enhancement are extraneous to the task of reducing the threshold, and their discussion usually leads to unnecessary confusions. While increasing $\beta$ is often presented as a way to reduce the laser threshold, this is almost always achieved by reducing the active volume of the laser, which keeps the all-important pumping density per unit of volume constant. Similarly, Purcell enhancement does not help, as both stimulated and spontaneous emission rate increase by the same amount.62 Note that to increase $F$, one needs to increase its FSR and decrease its mode volume.

The determination of the threshold in a microcavity is complicated by the large spontaneous emission coupling factor inherent in the devices with a small volume. The transition from spontaneous to stimulated emission dominated regime occurs in any laser, irrespective of implementation, when $\kappa_{tot} > 1$. This has been referred to as the quantum threshold condition in the context of microcavities, where it was rigorously shown that when $\kappa_{tot} > 1$, the autocorrelation function $g^{(2)}$ approaches unity, and the laser radiation can be described as a coherent state. Experimentally, the threshold is manifested as narrowing of the emission line width by a factor of 2 as coherent stimulated emission surpasses the incoherent spontaneous emission. Measurement of the line width provides the most reliable way to confirm the threshold, but it has often been overlooked when claims of lasing threshold were made based solely on the change of the slope of the input/output curve.23,32

Cavity Quantum Yield and $\beta$ Factor. In the simplest model of a multimode cavity, $QY_{em}$ is defined as

$$QY_{em} = \frac{\sum \kappa_{i}^{-1}(N)}{\sum \kappa_{i}^{-1}(N) + \tau_{fs}^{-1}(N) + \tau_{nr}^{-1}(N)}$$

(12)

where $\kappa_{i}$ is the spontaneous emission coupling factor for the $i$th mode, $\tau_{fs}$ is the stimulated emission rate, and $\tau_{nr}$ is the nonradiative lifetime. From now on, $\kappa_{i}$ is noted $\kappa_{i}$ for convenience. The radiative recombination rate is the sum of emission into two channels: free space and cavity modes. Thus, $\tau_{i}^{-1} = \tau_{fs}^{-1} + \tau_{nr}^{-1}$.

Solving for the steady state (and neglecting EEA, i.e., $\tau_{fs} = 0$), the pump rate can be derived

$$G = \frac{\eta_{tot}}{\beta} \left( 1 + \frac{\beta \eta_{tot}}{1 + \eta_{tot}} \right) + R_{\text{defects}}$$

(6)

where $R_{\text{defects}} = \frac{\eta_{tot}}{\beta} \left( \frac{1 + \beta \eta_{tot}}{1 + \eta_{tot}} \right) \left( \frac{\tau_{fs}}{\tau_{nr}} \right)$ is the nanoradiative recombination rate.

For an ideal laser ($\beta = 1$), the pump rate needed to satisfy the quantum threshold condition $\kappa_{tot} = 1$ is

$$G_{th,\text{ideal}} = \kappa_{tot} + R_{\text{defects}} = \kappa_{tot} \left( 1 + \frac{\tau_{fs}}{\tau_{nr}} \right) > \kappa_{tot}$$

(7)

where $R_{\text{defects}}$ can be neglected for a defectless microcavity, provided that $\frac{\tau_{fs}}{\tau_{nr}} \ll 1$.

Thus, the lowest possible threshold to achieve $\kappa_{tot} = 1$ in the lasing mode (for an optically pumped ideal single mode laser), $G_{th,\text{ideal}}$, is given by a pump flux that equals or exceeds the cavity decay rate.28 For an optically pumped microcavity (assuming $\beta = 1$ and neglecting nonradiative losses), the pump rate of the cavity mode $G_{th} = P_{th}/h\omega_{p}$ (where $P_{th}$ is the threshold pump power, $h\omega_{p}$ the pump photon energy) should equal (no defects) or exceed the cavity decay rate (in units $s^{-1}$)

$$G_{th} = \frac{\omega_{lasing}/Q}{\sum \kappa_{i}^{-1}(N)}$$

(12)
where the photons absorbed and emitted into all longitudinal cavity modes are considered. If we call the total radiative contribution \( \tau_r^{-1}(N) = \sum \tau_r^{-1}(N) \) + \( \tau_{\text{EEA}}^{-1}(N) \), dividing the numerator and denominator of eq 12 by this radiative contribution gives

\[
QY_c = \frac{\sum \beta}{1 + \tau_r/\tau_{\text{EEA}}} = \frac{M \beta_{\text{eff}}}{1 + \tau_r/\tau_{\text{EEA}}} \tag{13}
\]

where \( M \) is the number of modes within the envelope of our cavity PL spectrum. Equation 13 expresses the relationship between the cavity \( QY \) and the effective \( \beta_{\text{eff}} \) factor.

**Quantum Yield Model and High Power Limitation.** We start with the rate equation for excitons:

\[
\frac{d\langle N \rangle}{dt} = \Gamma_p - \Gamma_r \langle N \rangle - \gamma_{\text{bs}} \langle N \rangle^2 \tag{14}
\]

where \( \langle N \rangle \) is the number of excitons and \( \gamma_{\text{bs}} \) is the exciton–exciton annihilation (EEA) rate. Note that \( \gamma_{\text{bs}} \) is not the conventional EEA rate (which has units \( \text{cm}^2/\text{s} \)); instead, it has the unit of \( 1/\text{s} \). Lastly, \( \Gamma_r = \tau_r^{-1} + \frac{\text{EEA}_{\text{tot}}^{-1}}{1} + \tau_{\text{rad}}^{-1} = (1 + F + F_{\text{rad}})\tau_{\text{rad}}^{-1} \).

The steady state solution of this equation yields

\[
\langle N \rangle = \frac{1}{2 \gamma_{\text{bs}}} \left( \sqrt{\frac{\Gamma_p^2}{4 \gamma_{\text{bs}}}} \Gamma_p - \Gamma_r \right) \tag{15}
\]

If we call that \( \Gamma_r^2/4\gamma_{\text{bs}} \) as \( \Gamma_0 \) (with \( \Gamma_0 = F_{\text{rad}} \gamma_{\text{rad}} - 2/4\gamma_{\text{bs}} \)), then eq 15 can be rewritten as

\[
\langle N \rangle = \frac{2\Gamma_0}{F_{\text{rad}} \tau_{\text{rad}}^{-1}} \left( 1 + \frac{\Gamma_p}{\Gamma_0} - 1 \right) \tag{16}
\]

We then get

\[
QY_c = \frac{\tau_r^{-1}(N)}{G} = \frac{F}{\eta_{\text{EEA}}} \frac{\Gamma_p}{\Gamma_0} \tag{17}
\]

where \( \eta_{\text{EEA}}(x) = 2 \sqrt{1 + \frac{F_{\text{rad}}}{x}} \). Expressed in terms of powers, we have \( P_r = h\omega F_0 \) and \( P = h\omega F_r \). Thus, we can reduce the following \( QY \), expression to two parameters: \( \eta_0(0) = \frac{F}{F_{\text{tot}}} = \frac{\tau_{\text{tot}}^{-1}(\tau_{\text{rad}}^{-1} + \tau_{\text{EEA}}^{-1} + \tau_{\text{rad}}^{-1})}{\tau_{\text{tot}}^{-1}(\tau_{\text{rad}}^{-1} + \tau_{\text{EEA}}^{-1} + \tau_{\text{rad}}^{-1})} \), the low power \( QY_x \), and \( P_0 \) the power level associated with EEA:

\[
QY_x(P) = \eta_0(0) \left( \frac{2 \left( \sqrt{1 + \frac{P}{P_0}} - 1 \right)}{P_0} \right) \tag{18}
\]

At high power, a degradation of \( QY_x \), with increasing pump power can occur due to EEA. This model, taking both EEA as well as defect mediated nonradiative recombination into account, predicts a \( QY_x \) nonlinear power dependence at high power. We consider a generation-recombination rate balance

\[
G = R_{\text{rad,exc}} + R_{\text{trap,exc}} + R_{\text{EEA,exc}} = \tau_r^{-1}(N) + \tau_{\text{EEA}}^{-1}(N) + \gamma_{\text{bs}}(N)^2
\]

where \( (N) \) is the number of excitons, \( \tau_{\text{rad}} \) is the nonradiative recombination time, and \( \gamma_{\text{bs}} \) is the EEA rate. The radiative recombination rate \( \tau_r^{-1}(N) \) is the sum of emission into two channels: free space and cavity modes. Thus, \( \tau_r^{-1} = \tau_{\text{rad}}^{-1} + \sum \tau_r^{-1} = \tau_{\text{rad}}^{-1} + \tau_{\text{cav}}^{-1} \). We then get

\[
QY_x = \frac{R_{\text{rad,exc}}}{G} = \frac{\tau_{\text{rad}}^{-1}(N) + \tau_{\text{EEA}}^{-1}(N) + \gamma_{\text{bs}}(N)^2}{\tau_r^{-1}(N) + \tau_{\text{EEA}}^{-1}(N) + \gamma_{\text{bs}}(N)^2} \tag{19}
\]

We can rewrite eq 19 in a more physically intuitive form (see eq 18) as

\[
QY_x(P) = \eta_0(0) \eta_{\text{EEA}}(P/P_b) \tag{20}
\]

where \( \eta_0(0) \) is \( QY_x \) at low exciton densities and \( \eta_{\text{EEA}}(P/P_b) \) is the \( QY \) reduction caused by EEA, with \( P_b \) being the associated power scale. At high power (>\( P_b \)), the model predicts a nonlinear dependence of \( QY_x \) on pump power. This will limit the efficiency of light sources based on 1L-WSe2.

**Author Information**

**Corresponding Author**

*E-mail: tobias.kippenberg@epfl.ch.*

**ORCID**

Clément Javerzac-Galy: 0000-0002-6816-1391

**Author Contributions**

C.J.-G. and A.K. contributed equally to this work.

**Notes**

The authors declare no competing financial interest.

**Data Availability.** The code and data used to produce the plots within this paper are available at DOI:10.5281/zenodo.1212439. All other data used in this study are available from the corresponding authors upon reasonable request.

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**References**


